

UNIVERSITY OF TECHNOLOGY, SYDNEY

DOCTORAL THESIS

**Development and Implementation of
Environmental Photoelectron Yield
Spectroscopy**

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Declaration of Authorship

I, Toby William SHANLEY, declare that this thesis titled, Development and Implementation of Environmental Photoelectron Yield Spectroscopy, and the work presented in it is my own.

- I certify that the work in this thesis has not previously been submitted for a degree nor has it been submitted as part of requirements for a degree except as fully acknowledged within the text.
- I also certify that the thesis has been written by me. Any help that I have received in my research work and the preparation of the thesis itself has been acknowledged. In addition, I certify that all information sources and literature used are indicated in the thesis.

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“Productive stupidity means being ignorant by choice.”

Martin Schwartz

UNIVERSITY OF TECHNOLOGY, SYDNEY

Abstract

Faculty of Science

School of Physics and Advanced Materials

Doctor of Philosophy

Development and Implementation of Environmental Photoelectron Yield Spectroscopy

by Toby William SHANLEY

Environmental photoelectron yield spectroscopy (EPYS) is a novel, low vacuum, surface analysis technique that probes the electronic structure of solid-gas interfaces. Unlike its conventional, ultra high vacuum counterparts that interrogate ideal surfaces in non-realistic conditions, EPYS enables real-time characterisation of dynamic surface processes in semi-realistic, reactive gaseous environments. This capability is a requirement for the technological progress and fundamental understanding of processes in nanotechnology, materials physics, chemistry and bio-sciences.

The system has been built and implemented from the outset of its existence at UTS. This project has contributed to the development of EPYS, and further developed a number of novel applications. Specifically, its application in elucidating the nature of four, fundamentally different physical phenomena is demonstrated. The thesis describes the origins of EPYS in ultra high vacuum photoelectron emission spectroscopy and the theoretical groundwork on which it is based. It also details the EPYS development, and demonstrates applications of the EPYS in the analysis of gas ionisation cascades, subsurface defects, surface termination, and adsorbate coverage.

The value of this study is partly in the instrumentation development itself, but also in the demonstration of its application in studies of material systems responding to their environments.

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Contents

Declaration of Authorship	ii
Abstract	iv
Acknowledgements	v
List of Figures	ix
Abbreviations	xvii
Contributing Publications	xix
Non-Contributing Publications	xx
1 Introduction	1
1.1 Project objectives and methodology	1
1.2 Thesis outline	1
2 Background and literature	3
2.1 Overview	3
2.2 Photoelectron emission spectroscopy in modern surface science	4
2.3 Photoelectron spectroscopy (PES) in ultra high vacuum	5
2.3.1 History and development	5
2.4 Photoemission yield spectroscopy (PYS)	8
2.4.1 General theory	10
2.4.2 Theory of threshold determination	12
2.5 Surface characterisation	16
2.6 Atmospheric photoelectron yield spectroscopy	22
2.7 Townsend gas capacitance model	23
2.8 Limitations of existing knowledge	24
3 EPYS development	25
3.1 Overview	25
3.2 Introduction	25
3.3 Vacuum chamber	29
3.4 Sample stage	32
3.5 Detector	34
3.6 Light delivery	36
3.6.1 System response	37

3.7	Gas delivery	38
3.8	Automation and control	39
4	Application of EPYS: gas cascade amplification	41
4.1	Summary	41
4.2	Introduction	41
4.2.1	Gas amplification model	42
4.2.2	Positive feedback and breakdown	43
4.3	Experimental methods	44
4.3.1	ESEM	44
4.3.2	EPYS	45
4.4	Results	47
4.5	Discussion	50
4.5.1	Dependence of amplification on pressure	51
4.5.2	Dependence of amplification on detector bias	52
4.5.3	Ultimate amplification efficiency and dielectric breakdown	53
4.6	Conclusion	54
4.7	Implications	55
5	Application of EPYS: characterisation of subsurface defects and sensitivity to ambient gas	56
5.1	Summary	56
5.2	Introduction	57
5.2.1	Intrinsic point defects in ZnO	58
5.2.1.1	Oxygen vacancies	59
5.2.1.2	Zinc vacancies	60
5.2.2	Optical properties	61
5.2.2.1	Near band edge luminescence	61
5.2.2.2	Defect luminescence	62
5.2.3	Electrical properties	63
5.3	Experimental methods	63
5.3.1	Sensitivity to NH ₃	64
5.4	Results	65
5.4.1	Sensitivity to NH ₃	68
5.5	Discussion	70
5.5.1	Sensitivity to NH ₃	75
5.6	Conclusion	76
5.7	Implications	77
6	Application of EPYS: in-situ study of surface functionalisation	79
6.1	Summary	79
6.2	Introduction	79
6.2.1	Nitrogen-vacancy centre in diamond	80
6.2.2	Hydrogen and fluorine terminated diamond	82
6.2.2.1	Hydrogen terminated diamond	82
6.2.2.2	Fluorine terminated diamond	84
6.3	Experimental methods	86

6.3.1	Thermally activated fluorination	87
6.3.2	Electron beam induced fluorination	87
6.4	Results	88
6.5	Discussion	91
6.6	Conclusion	93
6.7	Implications	93
7	Application of EPYS: monitoring adsorbate coverage	95
7.1	Summary	95
7.2	Introduction	95
7.2.1	CO oxidation reaction	96
7.2.2	CO on platinum	97
7.3	Experimental methods	99
7.4	Results	101
7.5	Discussion	105
7.6	Conclusion	109
7.7	Implications	109
8	Conclusion	110
A	Townsend gas capacitance model	112
B	EPYS Standard Operating Procedure	119
B.1	Purpose	119
B.2	Procedures	119
B.2.1	Venting EPYS Chamber	119
B.2.2	Removing/Loading samples into EPYS Chamber	120
B.2.3	Pumping EPYS Chamber	120
B.2.4	Operating EPYS Chamber	121
B.2.4.1	Introducing Gas	121
B.2.4.2	Set-up Light Delivery	122
B.2.4.3	Set-up Detector Voltage and Begin Measurement	123
B.2.4.4	Finish Measurement	124
B.3	Heating and Cooling Sample Stage	124
B.3.1	Heating	125
B.3.2	Cooling	126
B.4	Calibrate Light Delivery	127
B.4.1	Gathering System Response	128
B.5	Troubleshoot LabView – Instrument Communication Errors	128
B.5.1	Monochromator	128
B.5.2	Beam Chem Monitor	129
B.6	Troubleshoot Hardware Failure	129
B.7	Data Processing and Analysis	130
B.7.1	EPYS Spectral Analysis in Igor Pro	131
B.8	Using the EPYS Chamber for DC Plasma Treatment	131
	Bibliography	132

List of Figures

2.1	Representation of the photoelectron emission process. Together, the diagrams compare the initial energetic positions of electrons within a solid to the final energy distribution of free photoelectrons, when excited by a monochromatic light source of energy $h\nu$. on the x and y axis respectively, $N(E)$ represents the number of electrons, while E represents the energy of electrons; E_F represents the Fermi level within the sample; V_S is the energy required for an electron to escape the material surface; $\hbar\omega$ is the incident photon energy; E_K is kinetic energy of free photoelectrons in vacuum; Φ_S is the surface work function; and Φ_A is the energy of a free electron in vacuum reference to E_F . The difference between Φ_S and Φ_A is due to a dipole at solid-vacuum interface.	6
2.2	Diagram of energy versus density of states showing the relationship between the density of states of electrons within the valence band, the energy of excitation, and the total number of photoelectron emitted from a surface. The yield is the integral of the density of states between E_{VAC} and $h\nu$ below the E_{VAC} . This expression for the yield must also be scaled by the probability of an excited carrier's transport to, and escape from the surface.	9
2.3	Intersection of the 'optical surface' and the 'escape surface' from [67]. The region bound by these surfaces contain the k values for which the probability of excitation may be calculated. As electron energy E decreases, the circle of intersection shrinks to k_d , the momentum corresponding to photoelectron emission threshold energy.	13
2.4	Summary of Ballantyne's results for the threshold determination of PES from semiconductors and metals [55]. Notably, the yield from most semiconductors was predicted to increase linearly with the cube root of incident photon energy, and the yield from most metals was predicted to increase linearly with the square root of incident photon energy.	15
2.5	Density of states derived from PYS data on the Si (111) 2×1 reconstructed surface. The solid lines represent the total density of states and the dashed lines represent densities of individual states. Trace 1) is plotted against the logarithmic axis on the left and trace 2) is plotted against the linear axis on the right. The spectra revealed the presence of inter-bandgap, dangling bond states at the Si surface.	16

2.6	Comparison between PYS data and the electronic band structure it represents. (a) PYS spectra of GaAs(111): the solid line is the photoelectron yield and the dashed line is the derivative of the yield which represents the density of states. The lower dashed line is the derivative plotted against a linear vertical axis (right side). (b) the derivative of the yield plotted on a band diagram to highlight how energetic positions correspond to photoemission thresholds [70].	17
2.7	PYS spectra from Ristein et. al. showing photoelectron emission from inter-bandgap states at 4.4 eV, and enhanced photoelectron emission strength for NEA diamond attributed to exciton-phonon induced free electron generation at 5.485 eV.	18
2.8	PYS spectra from Ristein et al. of single crystal type IIb diamond (111) and (100) surfaces after exposure to hydrogen plasma [75]. The sharp increase at 5.54 eV marks the exciton absorption edge, and confirms a NEA.	19
2.9	Experimental setup of an atmospheric PYS system developed by Honda et al. [57].	21
2.10	Atmospheric PYS spectra of Phthalocyanine films upon repeated exposure to air and evacuation of the vacuum chamber. Honda et al. identified two separate photoelectron emission thresholds, and observed an increase in the ionisation potential upon exposure to air [57].	21
2.11	Atmospheric PYS spectra collected by Nakayama et al. showing an increase in the ionisation potential of single crystalline ruberene during photo-oxidation [81]. The increase in the ionisation potential was attributed to generation of polar oxide molecules and reversible physisorption of H ₂ O.	23
3.1	Photograph of the complete EPYS instrument.	27
3.2	Photographs of the EPYS system showing: (a) The EPYS chamber, wrapped in foil to enable uniform heating of the inner side walls, with a TMP connected to the front 8" port and a variety of feedthroughs for electrical connections and gas delivery; (b) The top flange that hosts the majority of feedthroughs and a sapphire window that is positioned above the sample and detector; (c) Light being directed through the sapphire window onto the sample inside the chamber. The diameter of the irradiated spot is 5 mm; (d) The vacuum side of the top flange which consists of an annular GED held in place with a Macor ring and a gas injection needle pointing towards the centre.	28
3.3	Photograph of the (a) back and (b) front of the EPYS chamber.	30
3.4	Schematic of the EPYS system showing: (i) a high voltage power supply connected to the detector; (ii) a Keithley electrometer that measures the current through the sample stage generated by the cascading photoelectrons; (iii) the controllable-flow pumping outlet for operating in low vacuum; (iv) the chamber window through which UV light is passed to the sample; (v) the detector; (vi) the controllable flow inlet from gas delivery lines; (vii) the sample stage, electrically grounded through the electrometer; (viii) the sample heater; and (ix) the current supply for temperature control.	31
3.5	Schematic of the chamber used in the EPYS instrument.	32

3.6	Diagram of the EPYS detector-sample geometry with the excitation source directed through the centre of the detector, onto the sample. Neutral gas molecules between the sample and detector are ionised by photoelectrons moving under the influence of an electric field.	35
3.7	Diagram of the path of light from the deuterium lamp, focused into a Czerny-Turner monochromator with a CaF_2 lens, then collimated and re-focused with CaF_2 lenses onto the delivery optic fibre.	36
3.8	Normalised intensity spectrum of light that is incident on the sample. . .	38
3.9	Diagram of the EPYS gas delivery system. MFCs are used to control the flow of pressurised gaseous sources, while a manual needle valve is adequate for liquid sources like H_2 and $\text{C}_3\text{H}_6\text{O}$	39
4.1	Schematic illustration of (a) an ESEM setup and secondary electron amplification in a gas ionisation cascade, (b) an EPYS vacuum chamber and (c) the EPYS measurement process. In both methods, emitted electrons are accelerated by an electric field between the sample and a detector anode, and are multiplied by ionising gas molecules. The EPYS chamber consists of a pumping system (not shown), gas inlet and outlet, specimen stage, heater, gas cascade detector, and an optical window. (d) Shows Lewis diagrams representing the number of valence electrons contributing to the interaction cross sections of H_2O , NH_3 and $\text{CH}_3\text{CH}_2\text{OH}$	45
4.2	Gas-amplified electron emission current measured versus pressure using ethanol, NH_3 and H_2O . (a) In ESEM, the current is a sum of two components ($I_{\delta+\eta}$) that correspond to cascade-amplified, low energy ($\lesssim 20$ eV) secondary electrons and high energy (keV) backscattered electrons. (b) In EPYS the current (I_p) is generated purely by low energy ($\lesssim 7$ eV) photoelectrons. The detector anode bias was 400 V in both cases.	46
4.3	Gas-amplified electron emission current (I_Σ) and ($I_{\delta+\eta}$) measured versus ESEM detector anode bias using ethanol, NH_3 and H_2O , at gas pressures of (a) 0.1 Torr, (b) 1 Torr, and (c) 5 Torr. The maximum $I_{\delta+\eta}$ reached at the onset of dielectric breakdown of each gas is shown for each pressure on the plots.	48
4.4	Gas-amplified photoelectron emission current (I_p) measured versus EPYS detector anode bias using ethanol, NH_3 and H_2O , at gas pressures of (a) 0.1 Torr, (b) 1 Torr, and (c) 5 Torr. The maximum current reached at the onset of dielectric breakdown of each gas is shown for each pressure on the plots. The three amplification regimes (i, ii and iii) labelled on the plots are discussed in the main text.	49
4.5	Images taken at high and low magnification in (a) and (b): H_2O , (c) and (d): NH_3 , (e) and (f): ethanol vapour. The sequences verify that little to no carbon deposition occurs during electron beam irradiation in the presence of ethanol.	50
5.1	Charge states and transition levels of intrinsic point defects in ZnO. The charge states depend on value of the Fermi level. Figure adapted from Janotti and van der Walle [172].	59
5.2	Formation energies of native point defects in ZnO calculated by Janotti et al. [175]. The formation energies are plotted as a function of the Fermi level position in oxygen (left) and zinc (right) rich conditions. The different slopes of the traces represent different charge states.	60

- 5.3 Characteristic cathodoluminescence profile from ZnO at room temperature showing the near band edge emission at 3.37 eV and defect related emission arising from inter-bandgap radiative recombination pathways. 61
- 5.4 SEM images of nanorods thermally annealed in (a) O₂ environment (b) Zn vapour environment. The mean diameter and hexagonal structure of the nanorods remains unchanged; however, a slight reorientation with respect to the substrate can be observed. (c) As-grown nanorods (inset highlights high density hexagonal <0001> growth) and (d) shows XRD patterns of as-grown, O₂ annealed and Zn annealed nanorods. Changes in the relative peak heights arise from a reorientation of the nanorods with respect to the substrate. Data collected by Suranan Anantachaisilp. 66
- 5.5 Cathodoluminescence spectra of ZnO nanorod samples. The yellow trace is a CL profile from as-grown ZnO nanorods and is dominated by the YL at 1.9 eV. The red trace is a CL profile from O₂ annealed nanorods and shows a large defect emission in the RL band (1.7 eV) and a smaller contribution from the GL (2.5 eV). The green trace is a CL profile from Zn vapour annealed nanorods (magnified by 4) and exhibits GL defect emission and a relatively strong NBE emission. Data collected by Suranan Anantachaisilp. 67
- 5.6 EPYS spectra of ZnO nanorods. The red trace shows an EPYS spectrum from as-grown nanorods, the green trace is from O₂ annealed nanorods and the blue trace is from Zn vapour annealed nanorods. Both thermally treated samples (O₂ and Zn vapour annealed) exhibited a significantly greater photoelectron emission current than as-grown nanorods. While as-grown and O₂ annealed nanorods both began to emit photoelectrons at 4.5 eV, the Zn vapour annealed nanorods exhibited a lower photoelectron emission threshold at 4.2 eV. 68
- 5.7 Electrical conductance sensitivity of ZnO nanorods to gaseous NH₃ for (a) as-grown; (c) O₂ annealed; and (e) Zn vapour annealed samples. Figures (b), (d) and (f) show the corresponding ratio of the change in conductivity as a function of NH₃ concentration. Data collected by Suranan Anantachaisilp. 69
- 5.8 EPYS spectra from as-grown ZnO nanorods collected in an environment transitioning from argon into gaseous NH₃. The blue traces were collected initially in a dry, argon environment, and the pale red traces were collected in a NH₃ environment. Inset shows the spectra on a log-linear scale. As the partial pressure of NH₃ increases, the photoelectron emission threshold decreases. The gaps in the spectra are periods during which NH₃ is introduced to the chamber: spectra were not collected during this period as the detector bias had to be adjusted to compensate for the changing amplification medium. 70
- 5.9 EPYS spectra from oxygen annealed ZnO nanorods collected in an environment transitioning from argon into gaseous NH₃. The blue traces were collected initially in a dry, argon environment, and the pale red traces were collected in a NH₃ environment. Inset shows the spectra on a log-linear scale. As the partial pressure of NH₃ increases, the photoelectron emission threshold decreases. 71

5.10	EPYS spectra from zinc annealed ZnO nanorods collected in an environment transitioning from argon into gaseous NH ₃ . The blue traces were collected initially in a dry, argon environment, and the pale red traces were collected in a NH ₃ environment. Inset shows the spectra on a log-linear scale. As the partial pressure of NH ₃ increases, the photoelectron emission threshold decreases.	71
5.11	Band diagrams for the as-grown, oxygen annealed and zinc annealed ZnO samples. The Fermi level sits higher with respect to the conduction and valence bands in oxygen annealed and zinc annealed samples, and the zinc annealed ZnO exhibits greater downward band bending due to the presence of V _o	74
6.1	The diamond crystal lattice structure (left) containing a NV defect and the electronic structure of the NV ⁻ in diamond (right) [211].	80
6.2	Characteristic photoluminescence spectra of the NV ⁻ (red) and NV ⁰ (blue) defects in diamond.	81
6.3	Electrical conductivity data from Maier et al. [248] showing the change in surface conductivity when hydrogen terminated diamond is exposed to air.	83
6.4	Top: Schematic of the hydrogenated diamond surface in contact with a H ₂ O overlayer taken from Maier et al. [248]. Bottom: Evolution of the band bending during the electron transfer process at the interface between diamond and the H ₂ O overlayer.	85
6.5	Photograph of the confocal photoluminescence setup used in this study. The lens in the foreground focuses excitation light into a 0.5 μm ² spot on the sample, and also collects the photoluminescence from the sample.	86
6.6	A schematic of the confocal photoluminescence setup used in this study. A 532 nm excitation laser is directed onto the sample, and its x-y position at the sample surface scanned using a piezoelectric scanning mirror. Emitted and reflected light returns along the path of the excitation laser until they are separated at a dichroic mirror. The photons generated by the sample are allowed to pass through the dichroic mirror, where they are detected by avalanche photodiodes for panchromatic mapping, and/or a spectrometer.	88
6.7	Normalised photoelectron yield spectra of H-terminated diamond (acquired in a H ₂ environment) and F-terminated diamond (acquired in NF ₃ vapour). The latter were generated by thermal (solid line) and electron beam (dashed line) induced fluorination.	89
6.8	(a) Schematic illustration of nanodiamonds before, during and after electron beam irradiation in NF ₃ vapour. (b) SEM image of a cluster of nanodiamonds. (c) PL spectra collected from virgin, H-terminated, and irradiated nanodiamonds (solid lines). (d) PL map showing the sample region that was irradiated by an electron beam. The dashed traces in (c) show 5 additional spectra acquired from the virgin and irradiated sample regions, illustrating the consistency of data collected from H-terminated and irradiated nanodiamonds.	90
6.9	Simplified schematic of a diamond surface terminated with hydrogen and fluorine. [E _{CB} = conduction band minimum, E _{VB} = valence band maximum, E _F = Fermi level, E _{VAC} = vacuum level, ξ = ionisation energy]	91

-
- 6.10 Illustration of the activation of near-surface NV^- defects in nanodiamonds by irradiation with an electron beam in the presence of NF_3 . Electron bombardment removes a protective water overlayer, and exposed bare hydrogen terminated diamond to NF_3 , which then undergoes a spontaneous exchange reaction, fluorinating the nanodiamonds. 92
- 7.1 Temporal evolution of reaction diffusion spiral waves. The fronts of the waves are where a CO oxidation reaction is taking place with adsorbed O^- on Pt. The dark lines are O^- covered and the white spaces are CO covered [294]. 97
- 7.2 Potential energy diagrams of the three chemisorbed states of CO on platinum. The binding strength decreases with increasing coverage due to adsorbate-adsorbate interactions. When there is less CO present, the adsorbate molecule binds more strongly with the Pt atoms (hybridised C-Pt bonds) and when there is more CO, the nature of the C-Pt bonding changes, resulting in a more weakly bound state. 98
- 7.3 Speculative schematic of how coverage of CO molecules on platinum atoms affects the CO-platinum bonding configuration (taken from Culver [296]). (1) represents the most strongly bound state in the lowest coverage regime, while (5) shows a weakly bound state situated between chemisorbed CO molecules. 99
- 7.4 Temperature-resolved EPYS spectra acquired while Pt was heated in a CO environment. The blue traces were collected at $\sim 47^\circ C$ the temperature was incrementally increased and recorded for each set of spectra until reaching $\sim 380^\circ C$, shown in red. After collecting spectra at $380^\circ C$, the temperature was decreased to $307^\circ C$ to check for reversibility. The inset is a log-linear plot of the same data that highlights the shifting photoelectron emission threshold. 101
- 7.5 Temperature-resolved EPYS spectra acquired while Pt was cooled in a CO environment. The light red traces were collected at $\sim 380^\circ C$, the temperature was allowed to decrease until reaching room temperature, shown in blue. The temperature was measured only at the start and end of this experiment due to the influence of measuring temperature on the EPYS signal integrity. The inset is a log-linear plot of the same data that highlights the decreasing photoelectron emission threshold. 102
- 7.6 Work function determined from the average of photoelectron emission thresholds collected as a function of sample temperature. The existence of different binding states can explain the nonlinear relationship between the observed work functions and temperature. 103
- 7.7 (Top) A repeat experiment monitoring the photoelectron emission from CO-covered Pt with increasing temperature in which O_2 was injected at $\sim 370^\circ C$. Upon O_2 injection, the work function immediately decreased, and then returned to its former CO covered state. (Bottom) The corresponding residual gas analysis of this experiment. The work function slowly returns to its high temperature CO-covered state as O_2 is depleted via the CO oxidation reaction. 104
- 7.8 Distribution of binding states of CO on Pt taken from Nishiyama [299]. . 107
- 7.9 Desorption kinetics of CO chemisorbed on Pt taken from Nishiyama [299]. 107

-
- A.1 Simulated $\alpha(z)$ curve [86] for typical gas cascade detector operating conditions ($d_{gap} = 8.5$ mm, $p = 5$ Torr and $V = 500$ Volts). Regions I to III represent different ionisation efficiencies as electrons move through the gap. Region I: no ionisation by low energy electrons near the sample surface; Region II represents increasing ionisation efficiency as electrons are accelerated under the electric field; Region III: swarm conditions and constant ionisation efficiency where energy gained under the influence of the electric field is equal to the energy loss from inelastic scattering collisions. 113
- A.2 Gas cascade amplification \mathcal{A} versus H_2O pressure as a function of (a) detector voltage at $d_{gap} = 5$ mm and (b) sample-detector separation distance. Figure adapted from [310] 116
- A.3 Gas cascade amplification \mathcal{A} versus (a) detector voltage at $d_{gap} = 5$ mm and (b) sample-detector separation distance calculated at four pressures: 2, 3, 4 and 5 Torr of H_2O . Figure adapted from [310]. 117

Abbreviations

AES	A uger E lectron S pectroscopy
APD	A valanche P hotodiode
ARPES	A ngle R esolved P hotoelectron E mission S pectroscopy
BSE	B ackscattered E lectron
CBM	C onduction B and M inimum
CCD	C harge C oupled D etector
CL	C athodoluminescence
DAP	D onor A ceptor P air
DAQ	D ata A cquisition
DOS	D ensity O f S tates
E_{CB}	E nergy of C onduction B and minimum
E_F	E nergy of F ermi level
E_V	E nergy of a free electron in V acuum
E_{VB}	E nergy of V alence B and maximum
EPYS	E nvironmental P hotoelectron (emission) Y ield S pectroscopy
ESEM	E nvironmental S canning E lectron M icroscope
FWHM	F ull W idth H alf M aximum
GED	G aseous E lectron D etector
GL	G reen L uminescence
LEED	L ow E nergy E lectron D iffraction
MFC	M ass F low C ontroller
NBE	N ear B and E dge
NEA	N egative E lectron A ffinity
NV	N itrogen V acancy
O_i	I nterstitial O xygen

PE	P rietary E lectron
PEA	P ositive E lectron A ffinity
PES	P hotoelectron E mission S pectroscopy
PI	P ositive I on
PID	P roportional- I ntegral- D erivative
PL	P hotoluminescence
PMT	P hotomultiplier T ube
PYS	P hotoelectron (emission) Y ield S pectroscopy
RGA	R esidual G as A nalyser
RL	R ed L uminescence
SE	S econdary E lectron
SEM	S canning E lectron M icroscope
SFG	S um F requency G eneration
SHE	S tandard H ydrogen E lectrode
TDS	T hermal D esorption S pectroscopy
TMP	T urbo M olecular P ump
UHV	U ltra H igh V acuum
UPS	U ltraviolet P hotoelectron (emission) S pectroscopy
UV	U ltraviolet
V_O	O xygen V acancy
V_{Zn}	Z inc V acancy
VBM	V alence B and M aximum
WRG	W ide R ange G auge
XANES	X -ray A bsorption N ear E dge S tructure
XPS	X -ray P hotoelectron (emission) S pectroscopy
XRD	X -ray D iffraction
YL	Y ellow L uminescence
Zn_i	I nterstitial Z inc
ZPL	Z ero P honon L ine

Contributing Publications

- Localized Chemical Switching of the Charge State of Nitrogen-Vacancy Luminescent Centers in Diamond, **Toby Shanley**, Aiden Martin, Igor Aharonovich, Milos Toth, *Applied Physics Letters* 105, 063103, Published 11 August 2014
- Role of Gas Molecule Complexity in Environmental Electron Microscopy and Environmental Photoelectron Yield Spectroscopy, **Toby Shanley**, Fadi Bonnie, John Scott, Milos Toth, *in submission*
- Band Structure of Stoichiometrically dissimilar ZnO surfaces, **Toby Shanley**, Suranan Anantachaisilpm Matthew Phillips, Milos Toth, *in submission*

Non-Contributing Publications

- Silicon Oxide Nanowire Growth Mechanisms Revealed by Real-Time Electron Microscopy, Miroslav Kolibal, Libor Novak, **Toby Shanley**, Milos Toth, Tomas Sikola, *Nanoscale* 8 266-275, Published 26 November 2015
- Synthesis of Luminescent Europium Defects in Diamond, Andrew Magyar, Wenhao Hu, **Toby Shanley**, Michael Flatte, Evelyn Hu, Igor Aharonovich, *Nature Communications* 5 3523, Published 24 March 2014